Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-226-7824

Inclosure Material:

Glass

Overall Length:

0.180 inches

Terminal Length:

1.000 inches

Overall Diameter:

0.150 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

600.0 reverse voltage, dc and 600.0 repetitive peak reverse voltage, peak total value and 420.0 reverse voltage, total rms

Current Rating Per Characteristic:

25.00 amperes source cutoff current absolute and 6.00 amperes source cutoff current outside diameter and 1.00 amperes forward current, average absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0